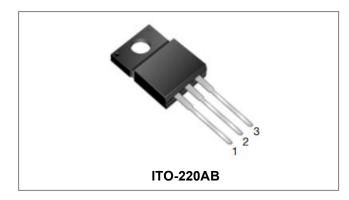


SDURF1040CTA(CTRA)

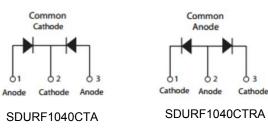
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SDURF1040CTA(CTRA) ULTRAFAST RECTIFIER



Circuit Diagram



Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Features

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	V _{RRM} V _{RWM}	-	400	V
DC Blocking Voltage	VR			
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=112°C, rectangular wave form	5(Per Leg) 10(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse	80	A

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V _{F1}	@5A, Pulse, TJ = 25°C	0.95	1.40	V
	V _{F2}	@5A, Pulse, TJ = 125°C	0.88	1.30	V
Reverse Current(Per Leg)*	I _{R1}	$@V_R = rated V_R$, $T_J = 25^{\circ}C$	0.04	30	μA
	I _{R2}	$@V_R = rated V_R$, $T_J = 125^{\circ}C$	0.015	1	mA
Reverse Recovery Time(Per Leg)	trr	I _F =500mA, I _R =1A,and I _m =250mA	30	35	ns

* Pulse width < 300 µs, duty cycle < 2%

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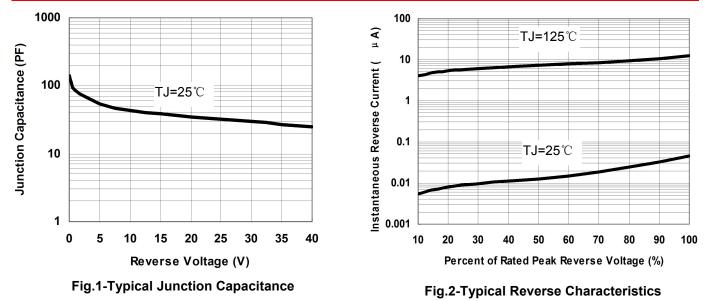
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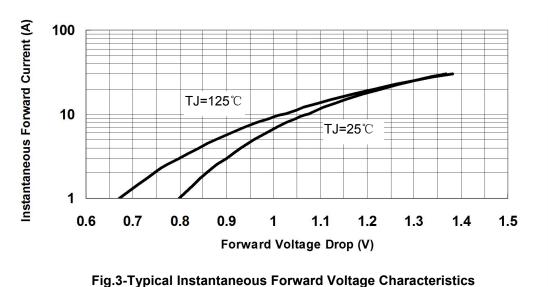
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Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	3.5	°C/W
Approximate Weight	wt	-	2	g
Case Style		ITO-220AB		

Ratings and Characteristics Curves





China - Germany - Korea - Singapore - United States
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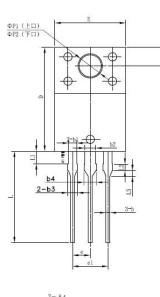


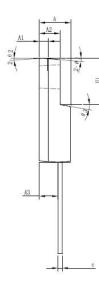
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Mechanical Dimensions ITO-220AB





CVMDOI	Millimeters				
SYMBOL	MIN.	TYP.	MAX.		
А	4.30	4.50	4.70		
A1	1.10	1.30	1.50		
A2	2.80	3.00	3.20		
A3	2.50	2.70	2.90		
b	0.50	0.60	0.75		
b1	1.10	1.20	1.35		
b2	1.50	1.60	1.75		
b3	1.20	1.30	1.45		
b4	1.60	1.70	1.85		
с	0.50	0.60	0.75		
D	14.80	15.00	15.20		
E	9.96	10.16	10.36		
e		2.55			
e1		5.10			
H1	6.50	6.70	6.90		
L	12.70	13.20	13.70		
L1	1.60	1.80	2.00		
L2	0.80	1.00	1.20		
L3	0.60	0.80	1.00		
ΦP1(上□)	3.30	3.50	3.70		
ΦΡ2 (下口)	2.99	3.19	3.39		
Q	2.50	2.70	2.90		
Θ1		5°			
Θ2		4°			
Θ3		10°			
Θ4		5°			
Θ5		5°			

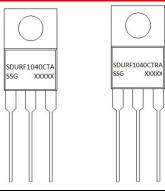
Ordering Information

Device	Package	Shipping
SDURF1040CTA(CTRA)	ITO-220AB (Pb-Free)	50 pcs/ tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

32mm

Marking Diagram



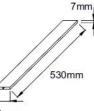
Where XXXXX is YYWWL

SDUR F 10 40 CTA(CTRA SSG YY WW	= Device Type = Package type = Forward Current (10A) = Reverse Voltage (400V)) = Configuration = SSG = Year = Week = L ot Number
L	= Lot Number
Cautions:	Molding resin Epoxy resin UL:94V-0

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Tube Specification





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